

PATENT  
Docket No. 150.00880102

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):	Derderian et al.	)	Group Art Unit:	2818
		)		
Serial No.:	10/042,025	)	Examiner:	Phuc Dang
Confirmation No.:	5745	)		
		)		
Filed:	October 25, 2001	)		
		)		
For:	METHODS FOR FORMING ROUGH RUTHENIUM-CONTAINING LAYERS <u>AND STRUCTURES/METHODS USING SAME</u>			

AMENDMENT AND RESPONSE

Assistant Commissioner for Patents  
Washington D.C. 20231

Dear Sir:

The Office Action mailed November 15, 2002 has been received and reviewed. Please amend the above-identified application as follows:

In the Claims

Please amend claim 37 as follows. The amended claim is provided below in clean form. Per 37 C.F.R. §1.121, the amended claim is also shown in Appendix A with notations to indicate changes made (for convenience, all pending claims are provided in Appendix A).

37.(Amended) The conductive structure of claim 36, wherein the surface of the rough ruthenium oxide layer has a surface area greater than about 1.5 times the surface area of the completely smooth surface having the substantially identical shape as the surface of the rough ruthenium oxide layer.